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Team Nexperia

NPN/NPN resistor-equipped transistors;

R1 = 22 kΩ, R2 = 22 kΩ

Rev. 5 — 2 December 2011

Product data sheet

1. Product profile

1.1 General description

NPN/NPN double Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1.	Product	overview

Type number	Package		NPN/PNP	PNP/PNP	Package
	NXP	JEITA	complement	complement	configuration
PEMH1	SOT666	-	PEMD2	PEMB1	ultra small and flat lead
PUMH1	SOT363	SC-88	PUMD2	PUMB1	very small

Reduces component count

AEC-Q101 qualified

Reduces pick and place costs

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
V _{CEO}	collector-emitter voltage	open base	-	-	50	V
lo	output current		-	-	100	mA
R1	bias resistor 1 (input)		15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	



23

sym063

1

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	GND (emitter) TR1		
2	input (base) TR1		
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		
6	output (collector) TR1	001aab555	

3. Ordering information

Table 4. Ord	lering inforn	nation	
Type number Package			
	Name	Description	Version
PEMH1	-	plastic surface-mounted package; 6 leads	SOT666
PUMH1	SC-88	plastic surface-mounted package; 6 leads	SOT363

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
PEMH1	H2
PUMH1	H*2

[1] * = placeholder for manufacturing site code

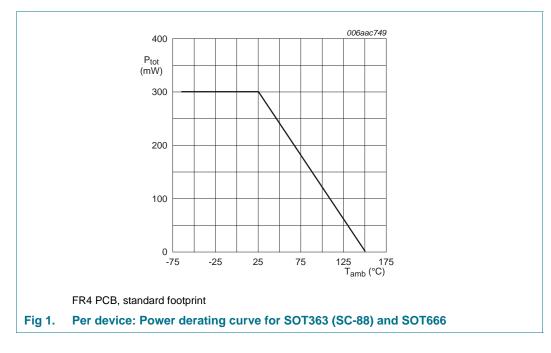
5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor				
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	10	V
VI	input voltage				
	positive		-	+40	V
	negative		-	-10	V
lo	output current		-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 \text{ ms}$	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \leq 25 ~^{\circ}C$			
	PEMH1 (SOT666)		[1][2] _	200	mW
	PUMH1 (SOT363)		<u>[1]</u> -	200	mW
Per device)				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PEMH1 (SOT666)		<u>[1][2]</u> _	300	mW
	PUMH1 (SOT363)		<u>[1]</u> -	300	mW
Т _ј	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω



6. Thermal characteristics

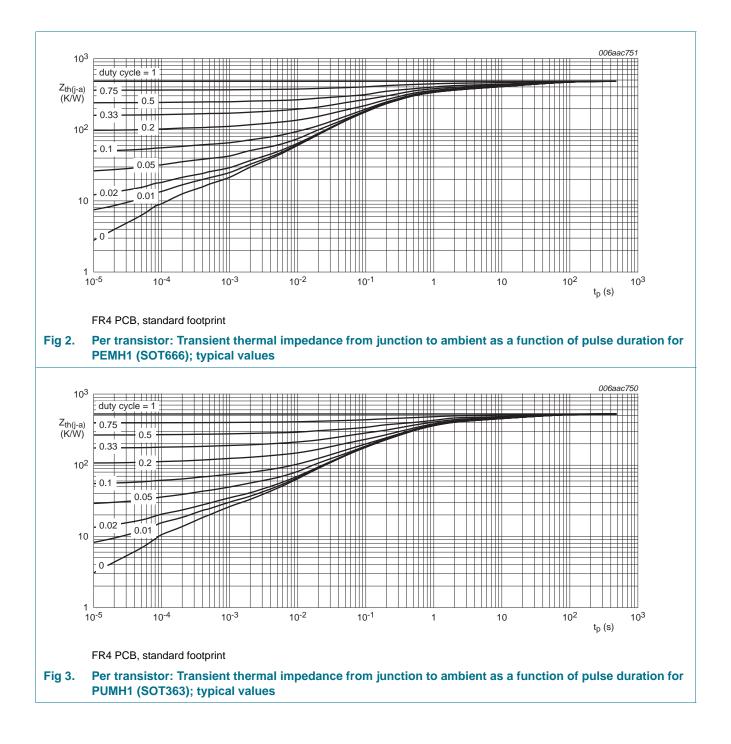
				_		
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Per trans	istor					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	PEMH1 (SOT666)		<u>[1][2]</u>	-	625	K/W
	PUMH1 (SOT363)		<u>[1]</u>	-	625	K/W
Per devic	e					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	PEMH1 (SOT666)		<u>[1][2]</u> _	-	417	K/W
	PUMH1 (SOT363)		<u>[1]</u> _	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

PEMH1; PUMH1

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω



7. Characteristics

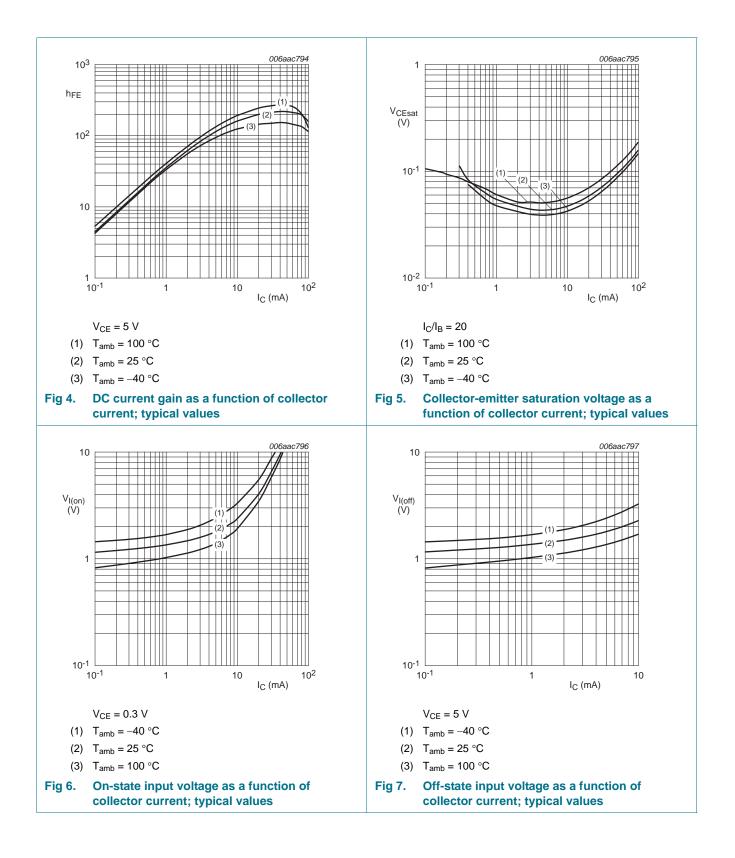
Table 8. $T_{amb} = 25$	Characteristics 5 ℃ unless otherwise spe	ecified.				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	sistor					
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I _{CEO}	collector-emitter cut-off	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}$	-	-	100	mA
	current	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-	-	5	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	180	μΑ
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	60	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_{C} = 10 mA; I_{B} = 0.5 mA	-	-	150	mV
V _{I(off)}	off-state input voltage	$V_{CE} = 5 \text{ V}; \text{ I}_{C} = 100 \mu\text{A}$	-	1.1	0.8	V
V _{I(on)}	on-state input voltage	V_{CE} = 0.3 V; I_{C} = 5 mA	2.5	1.7	-	V
R1	bias resistor 1 (input)		15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF
f⊤	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA};$ f = 100 MHz	<u>[1]</u> _	230	-	MHz

[1] Characteristics of built-in transistor

PEMH1_PUMH1 Product data sheet

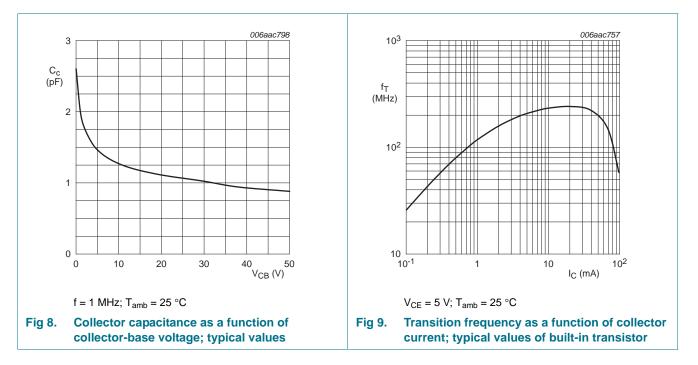
PEMH1; PUMH1

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω



PEMH1; PUMH1

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

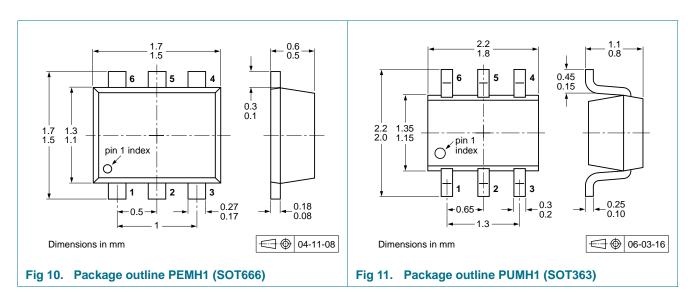


Test information 8.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Package outline 9.



PEMH1 PUMH1 **Product data sheet**

10. Packing information

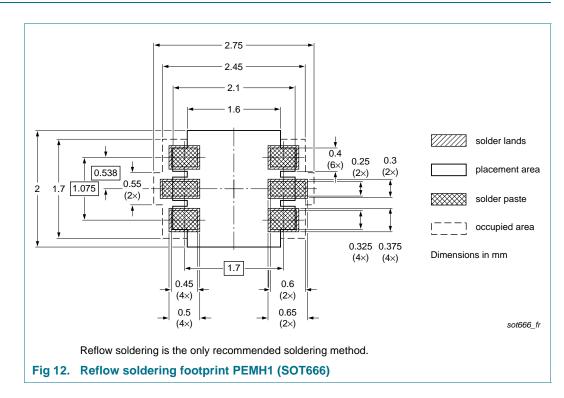
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

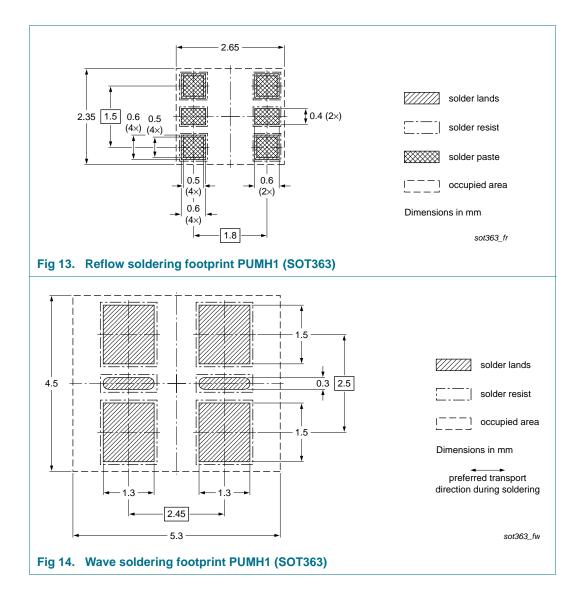
71 0		Description		Packing quantity			
number				3000	4000	8000	10000
PEMH1	SOT666	2 mm pitch, 8 mm tape and reel		-	-	-315	-
		4 mm pitch, 8 mm tape and reel		-	-115	-	-
PUMH1	SOT363	4 mm pitch, 8 mm tape and reel; T1	2]	-115	-	-	-135
		4 mm pitch, 8 mm tape and reel; T2	3]	-125	-	-	-165

- [1] For further information and the availability of packing methods, see Section 14.
- [2] T1: normal taping
- [3] T2: reverse taping

11. Soldering



NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω



PEMH1_PUMH1 Product data sheet

12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
PEMH1_PUMH1 v.5	20111202	Product data sheet	-	PEMH1_PUMH1 v.4				
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 							
	 Legal texts have been adapted to the new company name where appropriate. 							
	 <u>Section 1 "Product profile"</u>: updated 							
	 <u>Section 4 "Marking"</u>: updated 							
	• Figure 1 to 9: added							
	 <u>Section 6 "Thermal characteristics"</u>: updated 							
	 <u>Table 8 "Characteristics"</u>: V_{i(on)} redefined to V_{I(on)} on-state input voltage, V_{i(off)} redefined to V_{I(off)} off-state input voltage, I_{CEO} updated, f_T added 							
	 <u>Section 8 "Test information"</u>: added 							
	 <u>Section 9 "Package outline"</u>: superseded by minimized package outline drawings 							
	 <u>Section 10 "Packing information"</u>: added 							
	Section 11 °	 <u>Section 11 "Soldering"</u>: added 						
	Section 13	"Legal information": updated						
PEMH1_PUMH1 v.4	20031008	Product data sheet	-	PEMH1 v.1				
				PUMH1 v.3				
PEMH1 v.1	20011022	Preliminary specification	-	-				
PUMH1 v.3	19990520	Product specification	-	PUMH1 v.2				
PUMH1 v.2	19980806	Product specification	-	PUMH1 v.1				
PUMH1 v.1	19971212	Product specification	-	-				

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PEMH1 PUMH1

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

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PEMH1; PUMH1

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

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Date of release: 2 December 2011 Document identifier: PEMH1_PUMH1

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